

## APT15DQ120BHB APT15DQ120BHB(G) 1200V 2X15A

\*G Denotes RoHS Compliant, Pb Free Terminal Finish.

# **ULTRAFAST SOFT RECOVERY RECTIFIER DIODE**

#### **PRODUCT APPLICATIONS**

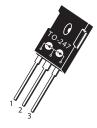
- Anti-Parallel Diode
   -Switchmode Power Supply
   -Inverters
- Free Wheeling Diode
   -Motor Controllers
   -Converters
   -Inverters
- Snubber Diode
- PFC
- RoHS Compliant

#### **PRODUCT FEATURES**

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- Popular TO-247 Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

#### PRODUCT BENEFITS

- Low Losses
- Low Noise Switching
- Cooler Operation
- Higher Reliability Systems
- Increased System Power Density



1 - Cathode 1 2 - Anode 1
Cathode 2 3 - Anode 2

#### MAXIMUM RATINGS

All Ratings per diode:  $T_{C}$  = 25°C unless otherwise specified.

Symbol	Parameter	Ratings	Unit
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	1200	V
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward Current (T <sub>c</sub> = 74°C, Duty Cycle = 0.5)	15	
I <sub>F(RMS)</sub>	RMS Forward Current (Square wave, 50% duty)	17	А
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current ( $T_{J} = 45^{\circ}C$ , 8.3ms)	110	
EAVL	Avalanche Energy (1A, 40mH)	20	mJ
T_,T <sub>stg</sub>	Operating and StorageTemperature Range	-55 to 175	°C
TL	Lead Temperature for 10 Sec.	300	U

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter		MIN	TYP	MAX	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 15A		3.0	3.5	
		I <sub>F</sub> = 30A		3.7		V
		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C		2.2		1
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = 1200V			100	
		V <sub>R</sub> = 1200V, T <sub>J</sub> = 125°C			500	μA
C <sub>T</sub>	Junction Capacitance, $V_{R}$ = 200V	V <sub>R</sub> = 200V		17		

CAUTION: These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

#### **DYNAMIC CHARACTERISTICS**

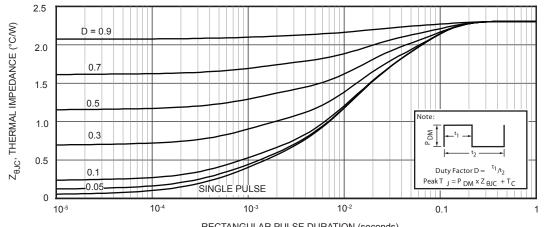
#### APT15DQ120BHB(G)

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 1A, di <sub>F</sub> /dt = -100A/μs V <sub>R</sub> = 30V, T <sub>J</sub> = 25°C		21		ns
t <sub>rr</sub>	Reverse Recovery Time	- I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -200A/μs - V <sub>R</sub> = 800V, T <sub>C</sub> = 25°C		240		
Q <sub>rr</sub>	Reverse Recovery Charge			260		nC
I <sub>RRM</sub>	Reverse Recovery Current			3		Amps
t <sub>rr</sub>	Reverse Recovery Time	- I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -200A/μs - V <sub>R</sub> = 800V, T <sub>C</sub> = 125°C		290		ns
Q <sub>rr</sub>	Reverse Recovery Charge			960		nC
I <sub>RRM</sub>	Reverse Recovery Current			6		Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15A, di <sub>F</sub> /dt = -1000A/μs V <sub>R</sub> = 800V, T <sub>C</sub> = 125°C		130		ns
Q <sub>rr</sub>	Reverse Recovery Charge			1340		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			19		Amps

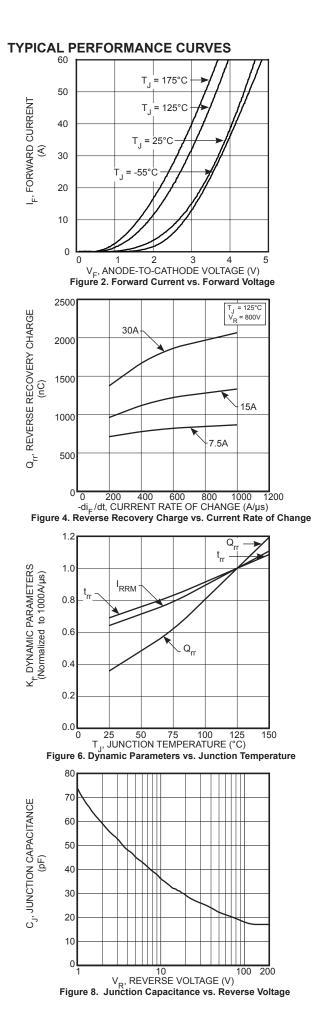
#### THERMAL AND MECHANICAL CHARACTERISTICS

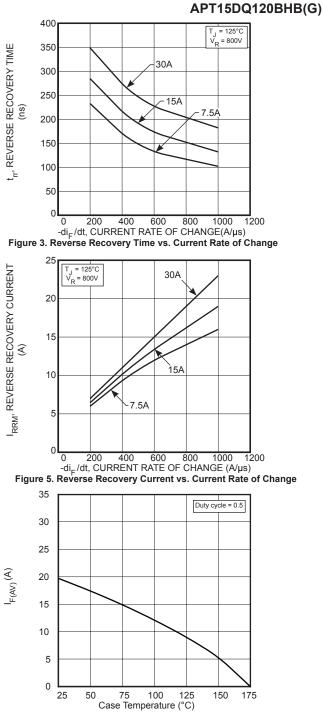
Symbol	Parameter	Min	Тур	Мах	Unit
R <sub>ejc</sub>	Reverse Recovery Time			2.3	°C/W
	Package Weight		0.22		oz
W <sub>T</sub>			5.9		g
Torque	Maximum Mounting Torque	Î		10	lb•in
				1.1	N•m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.



RECTANGULAR PULSE DURATION (seconds) FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION







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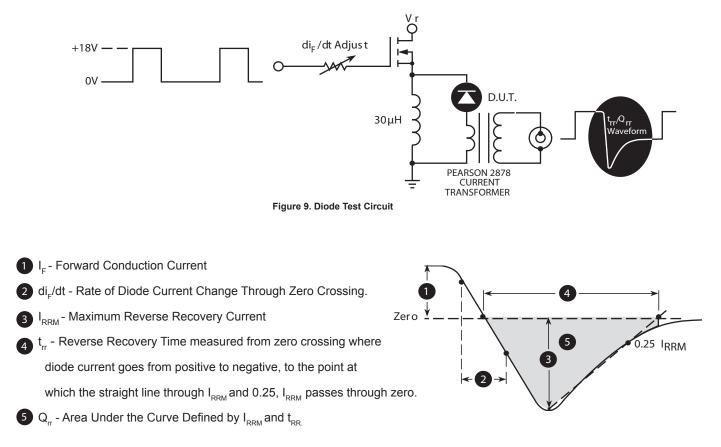
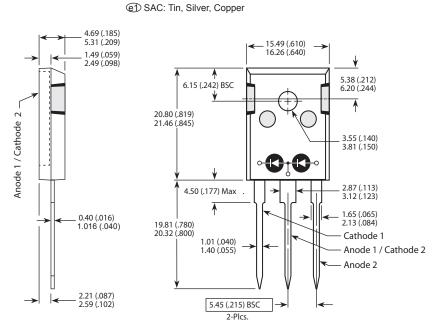


Figure 10. Diode Reverse Recovery Waveform Definition

### **TO-247 Package Outline**



Dimensions in Millimeters and (Inches)

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